# NSN 5961-00-188-4276

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Inclosure Material:

Metal

**Overall Length:** 

0.332 inches

#### **Overall Diameter:**

0.830 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc

# **Current Rating Per Characteristic:**

4.00 amperes base current, dc and 10.00 amperes collector current, dc

# **Power Rating Per Characteristic:**

150.0 watts total device dissipation

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

A110a0